

IGBT

Load Short Measurement Method

About this document

This application notes mainly to show the measurement method of load short circuit for IGBT.

Contents

1. Introduction.....	2
1.1 Overview.....	2
1.2 Arm Short-circuit.....	3
1.2.1 Reason and counter measure.....	3
1.3 Load Short Circuit (LSC).....	4
1.3.1 Method 1: IGBT with short circuit withstand capability.....	4
1.3.2 Method 2: Utilize output inductance characteristics.....	4
1.4 LSC Test Methodology.....	5
2. Output Result for LSC.....	6
2.1 Output Result comparison.....	6
3. IGBT Introduction.....	7
3.1 IGBT Wafer Outline.....	7
4. Conclusion.....	7

1. Introduction

1.1 Overview

The short circuit mechanism can be categorized into two types: Arm Short and Load Short. The distinction between these lies in where the short occurs, Arm Short refers to a short circuit internally within the inverter, while Load Short occurs at the output.

By conducting Load Short Circuit (LSC) measurements on IGBTs, engineers can evaluate their performance and robustness under such conditions. These tests are crucial for assessing factors like switching speed, current handling capabilities, and effectiveness of protection features. Additionally, load short-circuit testing helps identify and address issues such as excessive power dissipation, thermal stress, and potential failure modes, ensuring the reliability and durability of the IGBTs in practical applications.

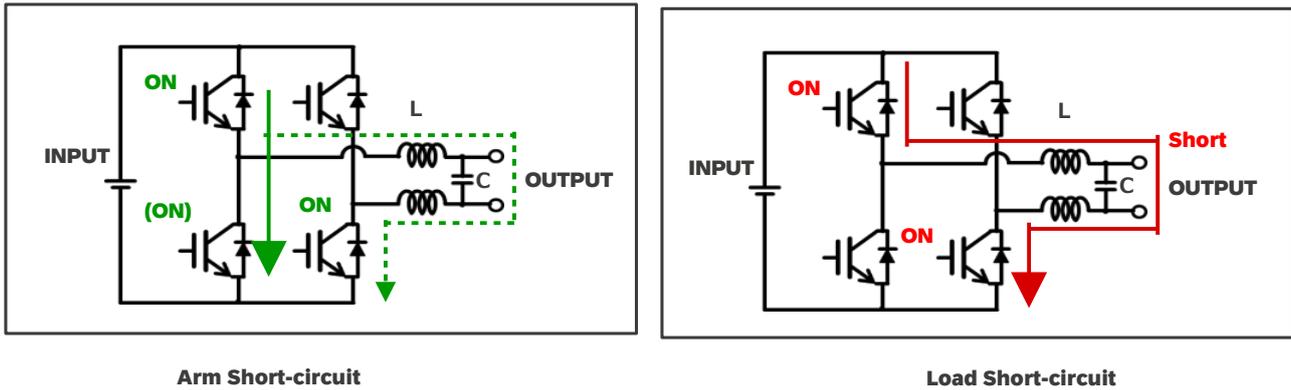


Figure 1-1 Short Circuit Mechanism

1.2 Arm Short-circuit

In a DC short circuit condition, current flows directly through the IGBT from the high side to the low side when both are turned on simultaneously. Figure 1.1. on the left-hand side illustrates the current flow diagram (Arm Short-circuit diagram).

1.2.1 Reason and counter measure

There are several reasons why short circuits occur. The table below outlines the main causes that can be prevented with appropriate margin and confirmation in the design.

Problem 1: Hi-side and Lo-side receiving ON signals simultaneously due to control IC miss operation.

Noise can disrupt the operation of the control IC and cause the simultaneous activation signals being sent to both the high-side and low-side components. Investigating and addressing the root cause of this miss operation, such as enhancing noise immunity or fine-tuning signal timing, can substantially lower the risk of short circuits occurring.

Problem 2: Hi-side and Lo-side switching times overlap.

When the switching times of the high-side and low-side IGBTs overlap, it can lead to short circuits or other unintended consequences. To prevent this, adjusting the deadtime between the switching of the IGBTs ensures that there is a sufficient delay between turning off one IGBT and turning on the other. Additionally, reducing the gate resistor (RG) helps to speed up the switching times of the IGBTs, minimizing the overlap period and improving the overall performance and reliability of the circuit.

Problem 3: High dv/dt causes an increase in VGE (gate-emitter voltage) and unintended turn-on of the IGBT.

High dv/dt conditions can lead to rapid changes in VGE, potentially triggering unintended turn-on of the IGBT. Applying a gate reverse bias during critical transitions helps to stabilize VGE and prevent unintended switching. Additionally, increasing the gate resistor (RG) slows down the switching times of the IGBT, which reduces the likelihood of dv/dt-induced turn-on, enhancing overall circuit reliability.

1.3 Load Short Circuit (LSC)

In an output short circuit, there is an unintended electrical path through the IGBT when it is conducting, allowing a current higher than normal to flow. This can lead to a short circuit, as illustrated in Figure 1.1. on the right (LSC diagram).

Load shorts usually occur due to end-user mistakes, which makes prevention challenging for design engineers. However, it's crucial to protect against such incidents even if they occur. Below are two methods that can help secure the circuits from damage

1.3.1 Method 1: IGBT with short circuit withstand capability

The short circuit withstand capability, often expressed as time short circuit (t_{sc}), refers to a component's ability to endure or handle a short circuit safely, without damage or posing a safety hazard. It measures how well the device can withstand the high currents and heat generated during a short circuit event without failing or breaking down. This capability depends significantly on factors such as gate-emitter voltage, case temperature, and power supply voltage. These factors should be carefully considered during circuit design.

Essentially, the IGBT is capable of withstanding a short circuit for a few microseconds. If the protective circuitry reacts within this timeframe, it can safeguard the inverter circuit.

1.3.2 Method 2: Utilize output inductance characteristics

An inductor is a passive electronic component that temporarily stores energy in a magnetic field when electric current flows through its coil. This characteristic allows the inductor to extend the period over which the current rises to levels that could potentially damage the IGBT.

Further, additional protection circuit can be adding to prevent the IGBT destruction before current rises to the short circuit failure level.

The graph below illustrates the conceptual of t_{sc} with inductor, which depends on the defined value of inductance.

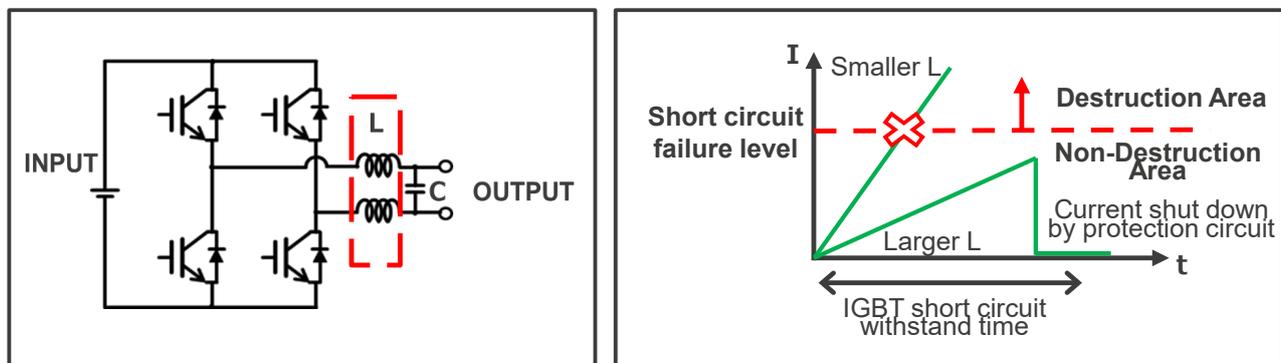


Figure 1-2 Conceptual of t_{sc} with inductor

1.4 LSC Test Methodology

Below is the circuit diagram that will be used to explain the procedure of the LSC test method.

Test condition: $V_{CC} = 600V$, $V_{GE} = 15V$, $R_G = 25 \Omega$, $T_c = 25 \text{ }^\circ\text{C}$

The forward bias voltage and pulse width (t_{sc}) between the gate and emitter are adjusted to the specified values to turn the IGBT on. Subsequently, the IGBT is turned off by applying the specified reverse bias voltage between the gate and emitter. Changes in t_{sc} are monitored during this process.

Next, the product undergoes validation to ensure the IGBT withstands the rated short circuit safe operating area, allowing observation of the IGBT's condition.

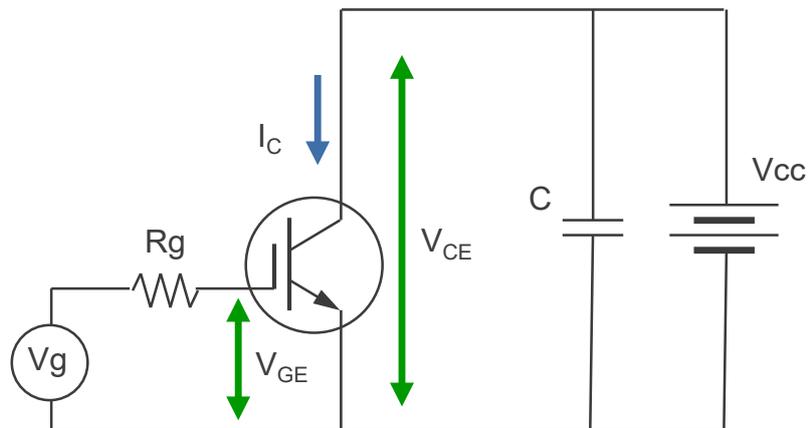


Figure 1-3 Circuit diagram for LSC

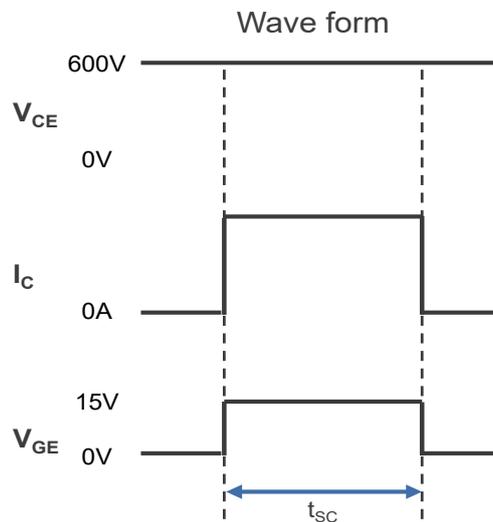


Figure 1-4 Theoretically Waveform

2. Output Result for LSC

2.1 Output Result comparison

Below are the output results of the LSC measurements captured from the oscilloscope. Figure 2.1.1. shows the output for a non-destruction result, while Figure 2.1.2. demonstrates a destruction result by configuring with the additional condition such as t_{sc} , RG and snubber circuit.

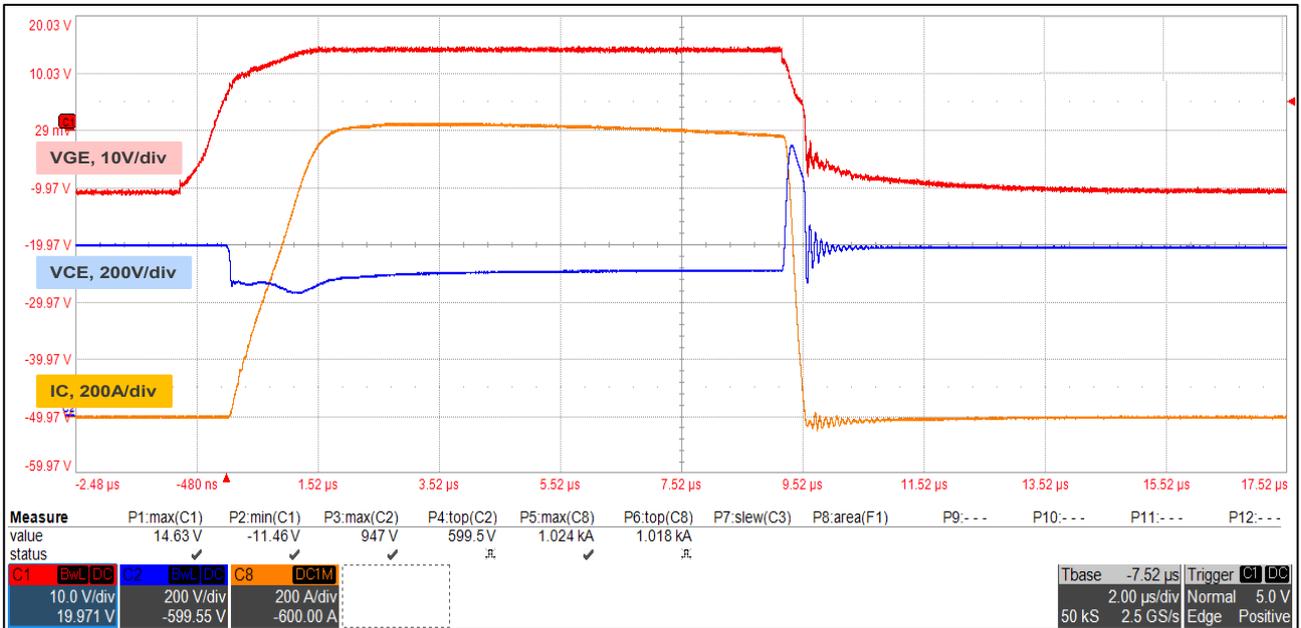


Figure 2-1 Non-destruction result

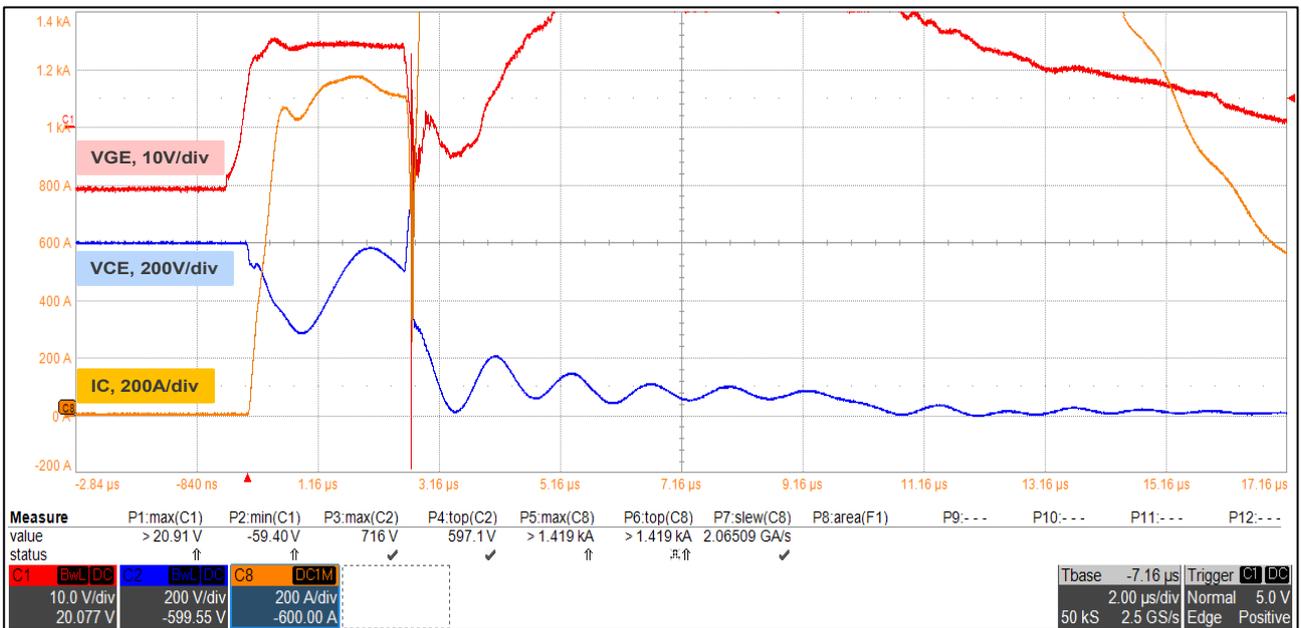


Figure 2-2 Destruction result

3. IGBT Introduction

The IGBT wafer (RJP1CS08DWA) has been selected for this LSC measurement, with a voltage capability of 1250V and a power switching capacity of 200A.

- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.8V$ typ. (at $I_C = 200A$, $V_{GE} = 15V$)
- High speed switching
- Short circuit withstands time (10 μs for min.)

3.1 IGBT Wafer Outline

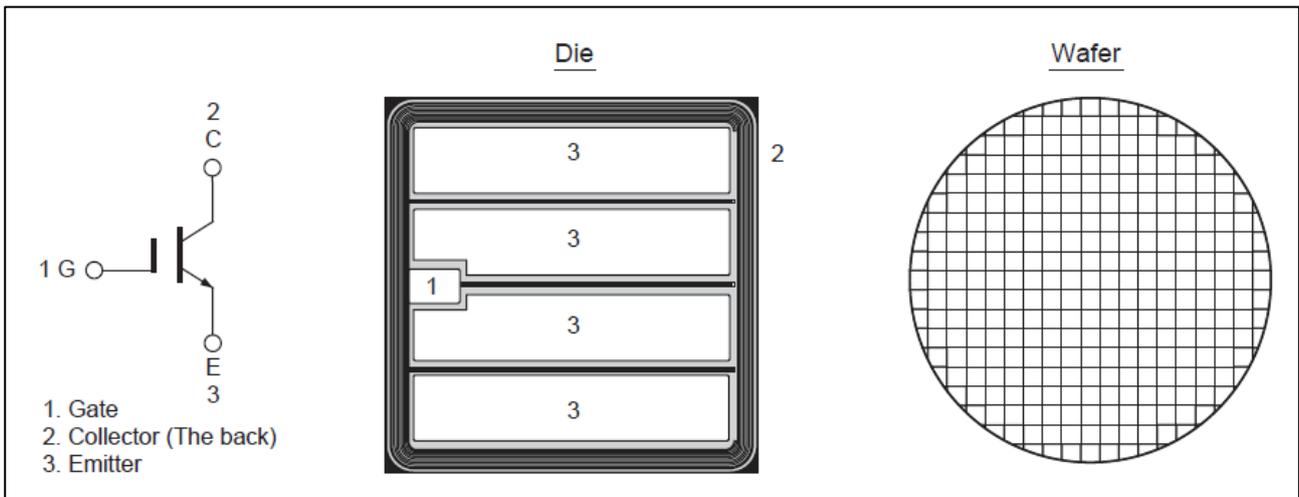


Figure 3-1 IGBT wafer outline

4. Conclusion

In conclusion, users have the option to select either the guaranteed IGBT or base their choice on the inductance characteristics to ensure circuit security. The decision should hinge on the specific design requirements, whether for 650V or 1250V applications, balancing considerations of reliability, performance, and cost. It is recommended, especially for high-capacity applications like 1250V, to prioritize the guaranteed IGBT short circuit withstand capability due to the potentially severe consequences of IGBT failure.

Revision History

Rev.	Date	Description	
		Page	Summary
1.00	Jul.29.24	-	First edition

Notice

1. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation or any other use of the circuits, software, and information in the design of your product or system. Renesas Electronics disclaims any and all liability for any losses and damages incurred by you or third parties arising from the use of these circuits, software, or information.
2. Renesas Electronics hereby expressly disclaims any warranties against and liability for infringement or any other claims involving patents, copyrights, or other intellectual property rights of third parties, by or arising from the use of Renesas Electronics products or technical information described in this document, including but not limited to, the product data, drawings, charts, programs, algorithms, and application examples.
3. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of Renesas Electronics or others.
4. You shall be responsible for determining what licenses are required from any third parties, and obtaining such licenses for the lawful import, export, manufacture, sales, utilization, distribution or other disposal of any products incorporating Renesas Electronics products, if required.
5. You shall not alter, modify, copy, or reverse engineer any Renesas Electronics product, whether in whole or in part. Renesas Electronics disclaims any and all liability for any losses or damages incurred by you or third parties arising from such alteration, modification, copying or reverse engineering.
6. Renesas Electronics products are classified according to the following two quality grades: "Standard" and "High Quality". The intended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below.
 - "Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; industrial robots; etc.
 - "High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control (traffic lights); large-scale communication equipment; key financial terminal systems; safety control equipment; etc.Unless expressly designated as a high reliability product or a product for harsh environments in a Renesas Electronics data sheet or other Renesas Electronics document, Renesas Electronics products are not intended or authorized for use in products or systems that may pose a direct threat to human life or bodily injury (artificial life support devices or systems; surgical implantations; etc.), or may cause serious property damage (space system; undersea repeaters; nuclear power control systems; aircraft control systems; key plant systems; military equipment; etc.). Renesas Electronics disclaims any and all liability for any damages or losses incurred by you or any third parties arising from the use of any Renesas Electronics product that is inconsistent with any Renesas Electronics data sheet, user's manual or other Renesas Electronics document.
7. No semiconductor product is absolutely secure. Notwithstanding any security measures or features that may be implemented in Renesas Electronics hardware or software products, Renesas Electronics shall have absolutely no liability arising out of any vulnerability or security breach, including but not limited to any unauthorized access to or use of a Renesas Electronics product or a system that uses a Renesas Electronics product. RENESAS ELECTRONICS DOES NOT WARRANT OR GUARANTEE THAT RENESAS ELECTRONICS PRODUCTS, OR ANY SYSTEMS CREATED USING RENESAS ELECTRONICS PRODUCTS WILL BE INVULNERABLE OR FREE FROM CORRUPTION, ATTACK, VIRUSES, INTERFERENCE, HACKING, DATA LOSS OR THEFT, OR OTHER SECURITY INTRUSION ("Vulnerability Issues"). RENESAS ELECTRONICS DISCLAIMS ANY AND ALL RESPONSIBILITY OR LIABILITY ARISING FROM OR RELATED TO ANY VULNERABILITY ISSUES. FURTHERMORE, TO THE EXTENT PERMITTED BY APPLICABLE LAW, RENESAS ELECTRONICS DISCLAIMS ANY AND ALL WARRANTIES, EXPRESS OR IMPLIED, WITH RESPECT TO THIS DOCUMENT AND ANY RELATED OR ACCOMPANYING SOFTWARE OR HARDWARE, INCLUDING BUT NOT LIMITED TO THE IMPLIED WARRANTIES OF MERCHANTABILITY, OR FITNESS FOR A PARTICULAR PURPOSE.
8. When using Renesas Electronics products, refer to the latest product information (data sheets, user's manuals, application notes, "General Notes for Handling and Using Semiconductor Devices" in the reliability handbook, etc.), and ensure that usage conditions are within the ranges specified by Renesas Electronics with respect to maximum ratings, operating power supply voltage range, heat dissipation characteristics, installation, etc. Renesas Electronics disclaims any and all liability for any malfunctions, failure or accident arising out of the use of Renesas Electronics products outside of such specified ranges.
9. Although Renesas Electronics endeavors to improve the quality and reliability of Renesas Electronics products, semiconductor products have specific characteristics, such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Unless designated as a high reliability product or a product for harsh environments in a Renesas Electronics data sheet or other Renesas Electronics document, Renesas Electronics products are not subject to radiation resistance design. You are responsible for implementing safety measures to guard against the possibility of bodily injury, injury or damage caused by fire, and/or danger to the public in the event of a failure or malfunction of Renesas Electronics products, such as safety design for hardware and software, including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult and impractical, you are responsible for evaluating the safety of the final products or systems manufactured by you.
10. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. You are responsible for carefully and sufficiently investigating applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive, and using Renesas Electronics products in compliance with all these applicable laws and regulations. Renesas Electronics disclaims any and all liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
11. Renesas Electronics products and technologies shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations. You shall comply with any applicable export control laws and regulations promulgated and administered by the governments of any countries asserting jurisdiction over the parties or transactions.
12. It is the responsibility of the buyer or distributor of Renesas Electronics products, or any other party who distributes, disposes of, or otherwise sells or transfers the product to a third party, to notify such third party in advance of the contents and conditions set forth in this document.
13. This document shall not be reprinted, reproduced or duplicated in any form, in whole or in part, without prior written consent of Renesas Electronics.
14. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products.

(Note1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its directly or indirectly controlled subsidiaries.

(Note2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.

(Rev.5.0-1 October 2020)

Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu,
Koto-ku, Tokyo 135-0061, Japan
www.renesas.com

Trademarks

Renesas and the Renesas logo are trademarks of Renesas Electronics Corporation. All trademarks and registered trademarks are the property of their respective owners.

Contact information

For further information on a product, technology, the most up-to-date version of a document, or your nearest sales office, please visit:
www.renesas.com/contact/.